MOC8021M, MOC8050M

6-Pin DIP Photodarlington Optocoupler (No Base Connection)

The MOC8021M and MOC8050M are photodarlington−type optically coupled optocouplers. The devices have a gallium arsenide infrared emitting diode coupled with a silicon darlington phototransistor.

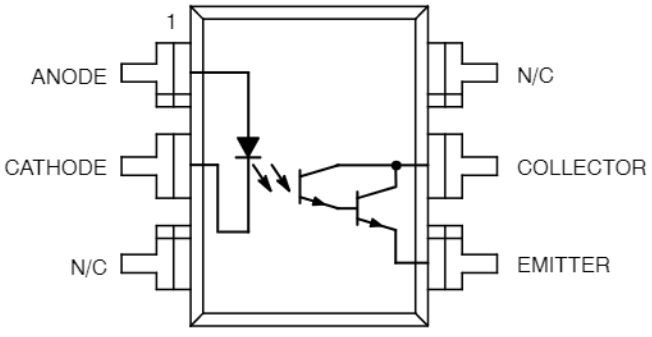
Features

- High BV_{CEO}:
  - Minimum 50 V (MOC8021M)
  - Minimum 80 V (MOC8050M)
- High Current Transfer Ratio:
  - Minimum 1000% (MOC8021M)
  - Minimum 500% (MOC8050M)
- No Base Connection for Improved Noise Immunity
- Safety and Regulatory Approvals:
  - UL1577, 4,170 VAC_{RMS} for 1 Minute
  - DIN−EN/IEC60747−5−5, 850 V Peak Working Insulation Voltage

Applications

- Appliances, Measuring Instruments
- I/O Interface for Computers
- Programmable Controllers
- Portable Electronics
- Interfacing and Coupling Systems of Different Potentials and Impedance
- Solid State Relays

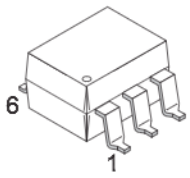
SCHEMATIC



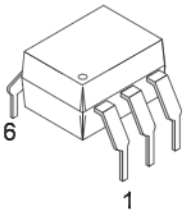
(Top View)

ON Semiconductor®

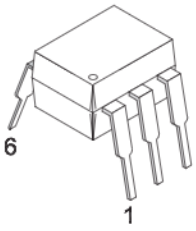
www.onsemi.com



PDIP6
CASE 646BY

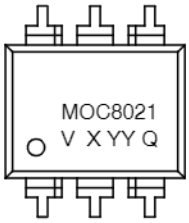


PDIP6
CASE 646BZ



PDIP6
CASE 646BX

MARKING DIAGRAM



MOC8021 = Device Code
V = DIN EN/IEC60747−5−5 Option (only appears on component ordered with this option)
X = One−Digit Year Code, e.g., “5”
YY = Digit Work Week, Ranging from “01” to “53”
Q = Assembly Package Code

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 7 of this data sheet.

Table 1. SAFETY AND INSULATION RATINGS

As per DIN EN/IEC 60747−5−5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Parameter		Characteristics
Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage	< 150 V_{RMS}	I–IV
	< 300 V_{RMS}	I–IV
Climatic Classification		55/100/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V_{PR}	Input−to−Output Test Voltage, Method A, V_{IORM} x 1.6 = V_{PR}, Type and Sample Test with t_m = 10 s, Partial Discharge < 5 pC	1360	V_{peak}
	Input−to−Output Test Voltage, Method B, V_{IORM} x 1.875 = V_{PR}, 100% Production Test with t_m = 1 s, Partial Discharge < 5 pC	1594	V_{peak}
V_{IORM}	Maximum Working Insulation Voltage	850	V_{peak}
V_{IOTM}	Highest Allowable Over−Voltage	6,000	V_{peak}
	External Creepage	≥ 7	mm
	External Clearance	≥ 7	mm
	External Clearance (for Option TV, 0.4″ Lead Spacing)	≥ 10	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥ 0.5	mm
T_S	Case Temperature (Note 1)	175	°C
$I_{S,INPUT}$	Input Current (Note 1)	350	mA
$P_{S,OUTPUT}$	Output Power (Note 1)	800	mW
R_{IO}	Insulation Resistance at T_S, V_{IO} = 500 V (Note 1)	> 10^9	Ω

1. Safety limit values – maximum values allowed in the event of a failure.

Table 2. ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Units
TOTAL DEVICE			
T_{STG}	Storage Temperature	−40 to +125	°C
T_{OPR}	Operating Temperature	−40 to +100	°C
T_J	Junction Temperature	−40 to +125	°C
T_{SOL}	Lead Solder Temperature	260 for 10 seconds	°C
P_D	Total Device Power Dissipation @ T_A = 25°C	270	mW
	Derate above 25°C	2.94	mW/°C
EMITTER			
I_F	DC/Average Forward Input Current	60	mA
V_R	Reverse Input Voltage	3	V
P_D	LED Power Dissipation @ T_A = 25°C	120	mW
	Derate Above 25°C	1.41	mW/°C
DETECTOR			
I_C	Continuous Collector Current	150	mA
V_{CEO}	Collector−Emitter Voltage − MOC8021M	50	V
	Collector−Emitter Voltage − MOC8050M	80	V
P_D	Detector Power Dissipation @ T_A = 25°C	150	mW
	Derate Above 25°C	1.76	mW/°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 3. ELECTRICAL CHARACTERISTICS T_A = 25°C unless otherwise specified

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
EMITTER						
V_F	Input Forward Voltage	I_F = 10 mA		1.18	2.00	V
I_R	Reverse Leakage Current	V_R = 3.0 V		0.001	10	μA
DETECTOR						
BV_{CEO}	Collector−Emitter Breakdown Voltage (MOC8021M)	I_C = 1.0 mA, I_F = 0	50	100		V
	(MOC8050M)		80	100		V
BV_{ECO}	Emitter−Collector Breakdown Voltage	I_E = 100 μA, I_F = 0	5	10		V
I_{CEO}	Collector−Emitter Dark Current	V_{CE} = 60 V, I_F = 0			1	μA
C_{CE}	Capacitance	V_{CE} = 0 V, f = 1 MHz		8		pF

Table 4. TRANSFER CHARACTERISTICS T_A = 25°C unless otherwise specified

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
DC CHARACTERISTICS						
CTR	Current Transfer Ratio, Collector−to−Emitter (MOC8021M)	I_F = 10 mA, V_{CE} = 5 V	1,000			%
	(MOC8050M)	I_F = 10 mA, V_{CE} = 1.5 V	500			%
AC CHARACTERISTICS						
t_{on}	Turn−on Time	I_F = 5 mA, V_{CC} = 10 V, R_L = 100 Ω		8.5		μs
t_{off}	Turn−off Time	I_F = 5 mA, V_{CC} = 10 V, R_L = 100 Ω		95		μs

Table 5. ISOLATION CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
V_{ISO}	Input−Output Isolation Voltage	t = 1 Minute	4170			VAC_{RMS}
C_{ISO}	Isolation Capacitance	V_{I-O} = 0 V, f = 1 MHz		0.2		pF
R_{ISO}	Isolation Resistance	V_{I-O} = ±500 VDC, T_A = 25°C	10^{11}			Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

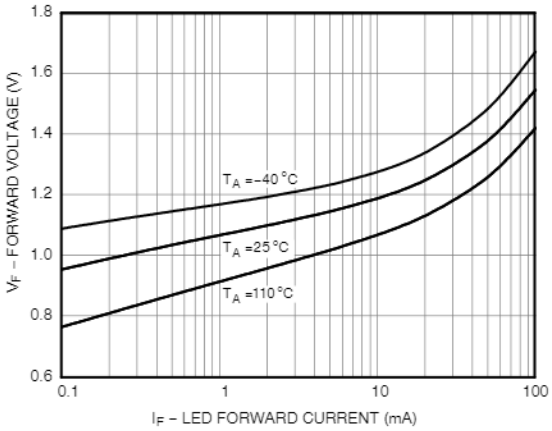


Figure 1. LED Forward Voltage vs. Forward Current

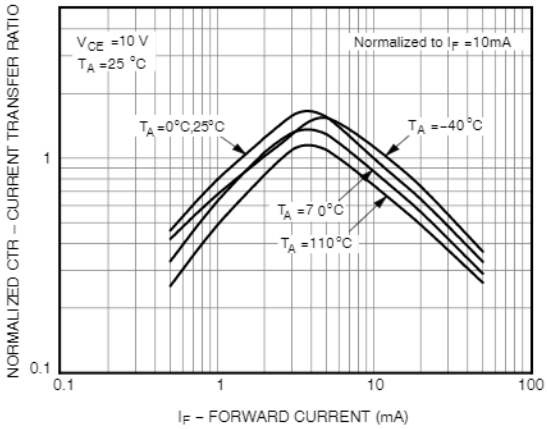


Figure 2. Normalized CTR vs. Forward Current

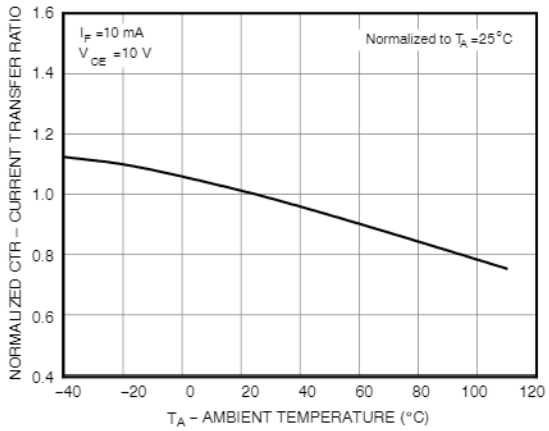


Figure 3. Normalized CTR vs. Ambient Temperature

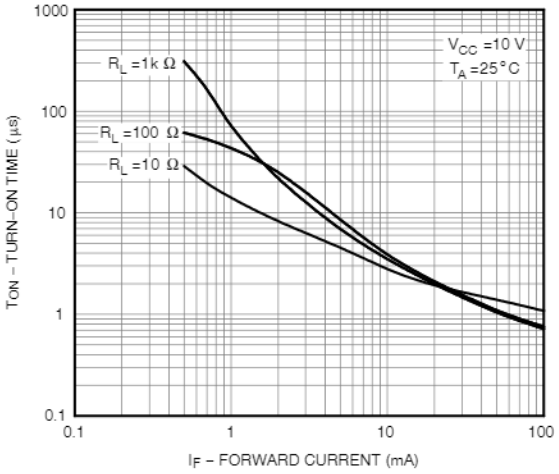


Figure 4. Turn–on Time vs. Forward Current

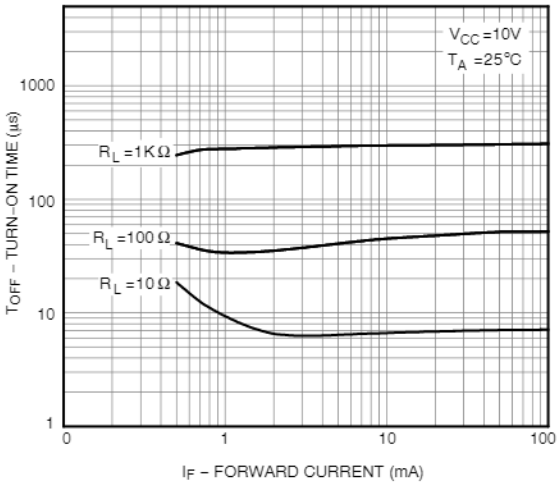


Figure 5. Turn–off Time vs. Forward Current

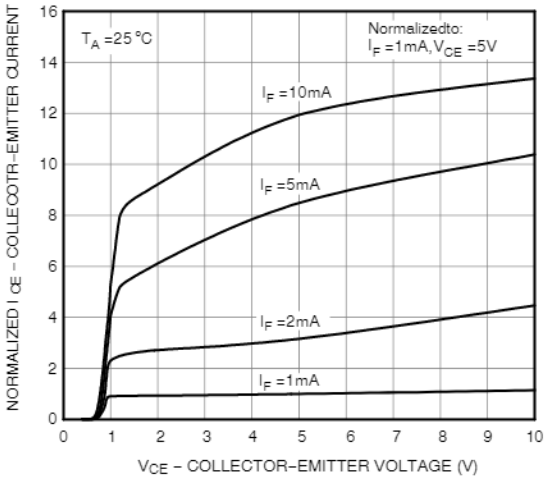


Figure 6. Normalized Collector–Emitter Current vs. Collector–Emitter Voltage

Typical Performance Curves (Continued)

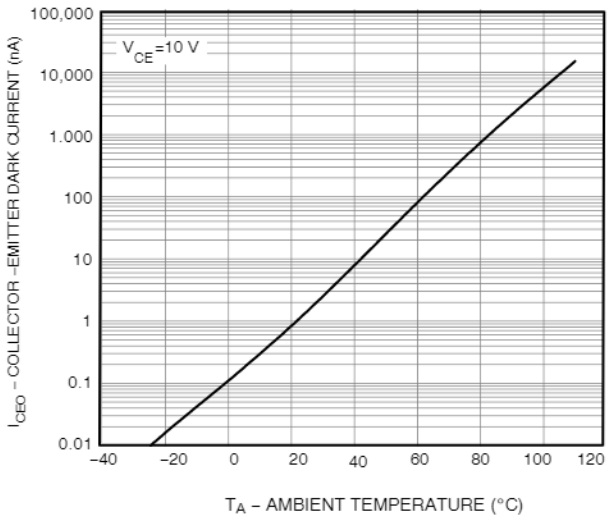


Figure 7. Dark Current vs. Ambient Temperature

Switching Time Test Circuit and Waveform

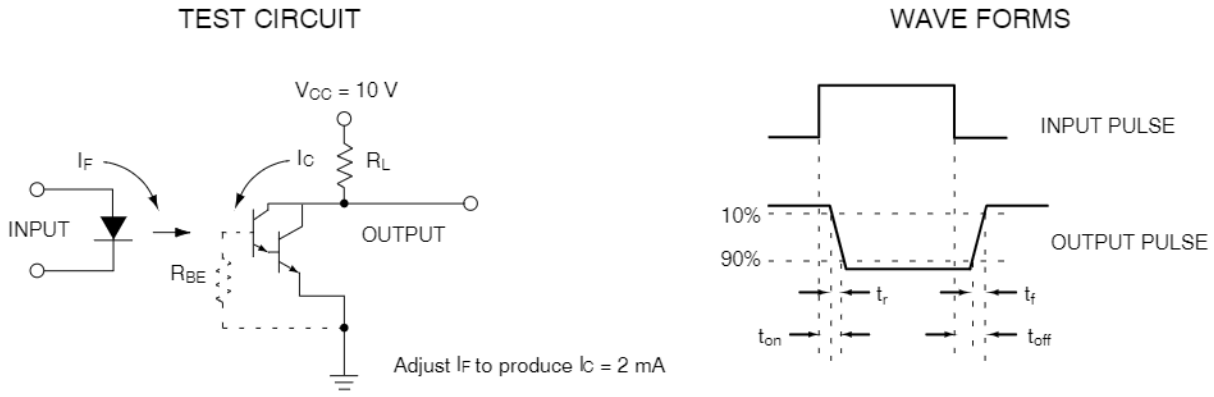


Figure 8. Switching Time Test Circuit and Waveform

REFLOW PROFILE

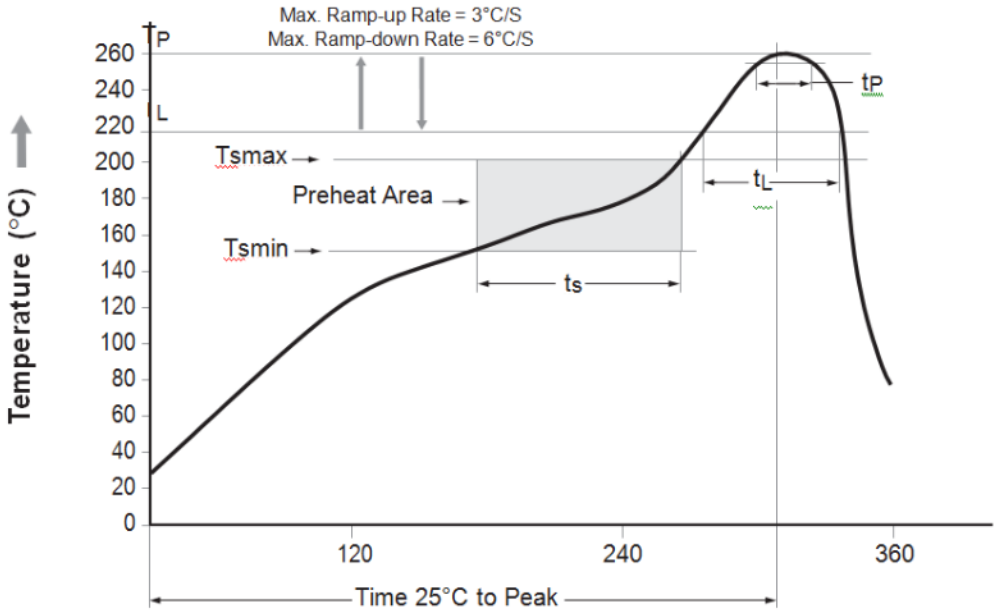


Figure 9. Reflow Profile

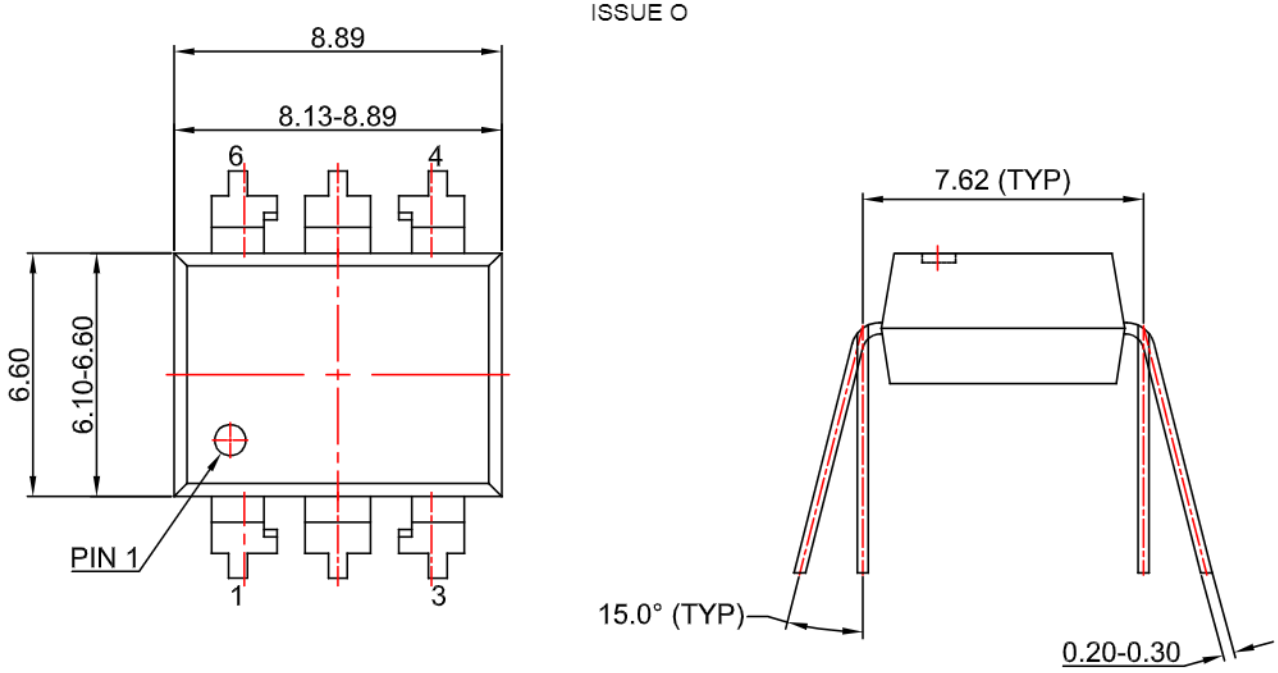
Profile Freature	Pb – Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t_S) from (Tsmin to Tsmax)	60–120 seconds
Ramp – up Rate (t_L to t_P)	3°C/second max.
Liquidous Temperature (T_L)	217°C
Time (t_L) Maintained Above (T_L)	60–150 seconds
Peak Body Package Temperature	260°C +0°C / –5°C
Time (t_P) within 5°C of 260°C	30 seconds
Ramp – down Rate (T_P to T_L)	6°C / second max.
Time 25°C to Peak Temperature	8 minutes max.

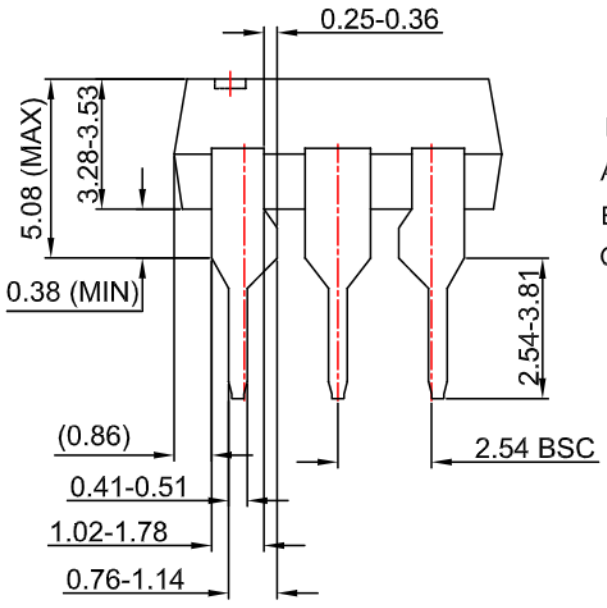
ORDERING INFORMATION

Part Number	Package	Packing Method
MOC8021M	DIP 6−Pin	Tube (50 Units)
MOC8021SM	SMT 6−Pin (Lead Bend)	Tube (50 Units)
MOC8021SR2M	SMT 6−Pin (Lead Bend)	Tape and Reel (1000 Units)
MOC8021VM	DIP 6−Pin, DIN EN/IEC60747−5−5 Option	Tube (50 Units)
MOC8021SVM	SMT 6−Pin (Lead Bend), DIN EN/IEC60747−5−5 Option	Tube (50 Units)
MOC8021SR2VM	SMT 6−Pin (Lead Bend), DIN EN/IEC60747−5−5 Option	Tape and Reel (1000 Units)
MOC8021TVM	DIP 6−Pin, 0.4″ Lead Spacing, DIN EN/IEC60747−5−5 Option	Tube (50 Units)
MOC8050M	DIP 6−Pin	Tube (50 Units)
MOC8050SM	SMT 6−Pin (Lead Bend)	Tube (50 Units)
MOC8050SR2M	SMT 6−Pin (Lead Bend)	Tape and Reel (1000 Units)
MOC8050VM	DIP 6−Pin, DIN EN/IEC60747−5−5 Option	Tube (50 Units)
MOC8050SVM	SMT 6−Pin (Lead Bend), DIN EN/IEC60747−5−5 Option	Tube (50 Units)
MOC8050SR2VM	SMT 6−Pin (Lead Bend), DIN EN/IEC60747−5−5 Option	Tape and Reel (1000 Units)
MOC8050TVM	DIP 6−Pin, 0.4″ Lead Spacing, DIN EN/IEC60747−5−5 Option	Tube (50 Units)

PACKAGE DIMENSIONS

PDIP6 8.51x6.35, 2.54P
CASE 646BX
ISSUE O





NOTES:

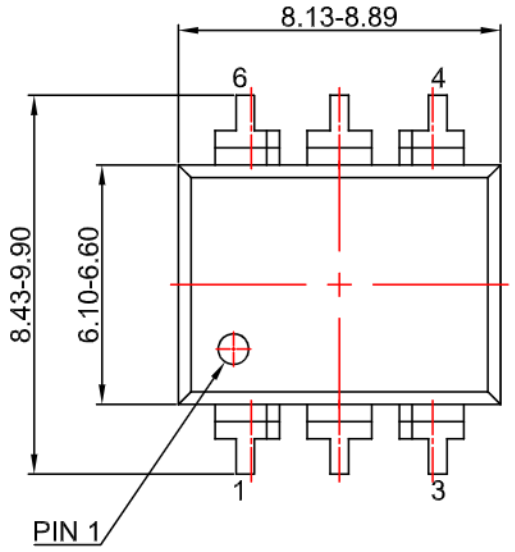
A) NO STANDARD APPLIES TO THIS PACKAGE.

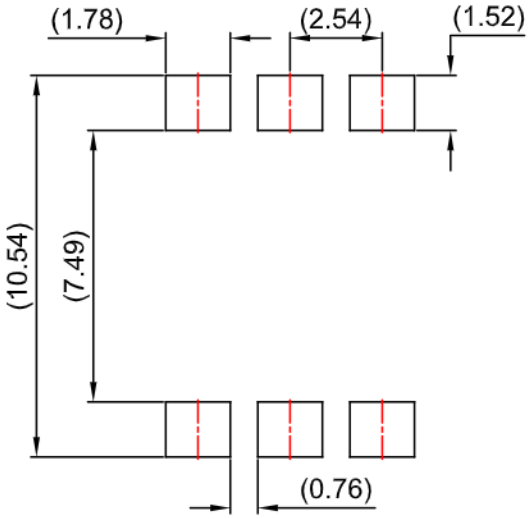
B) ALL DIMENSIONS ARE IN MILLIMETERS.

C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

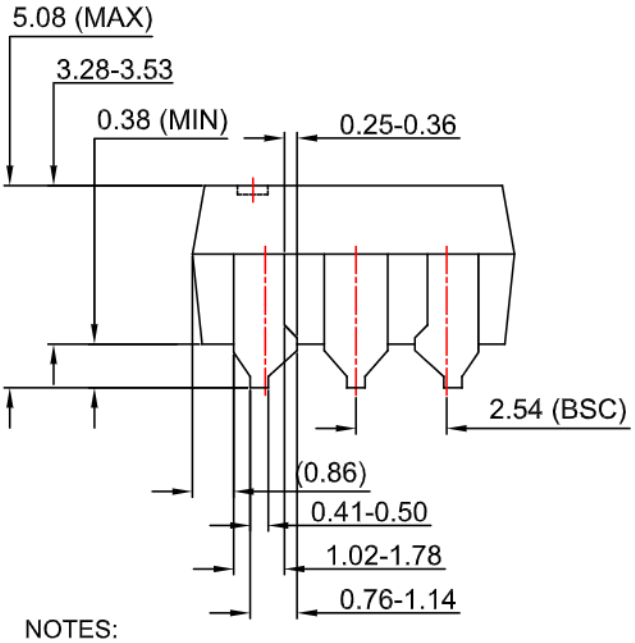
PACKAGE DIMENSIONS

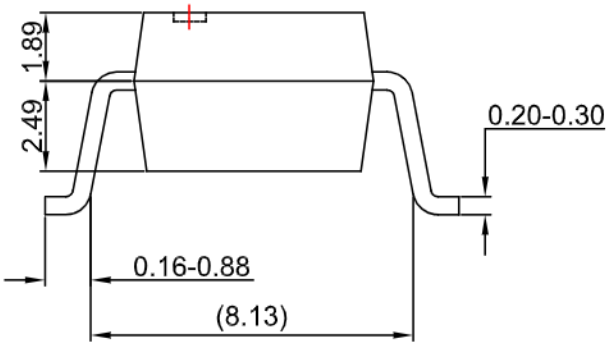
PDIP6 8.51x6.35, 2.54P
CASE 646BY
ISSUE O





LAND PATTERN RECOMMENDATION





NOTES:

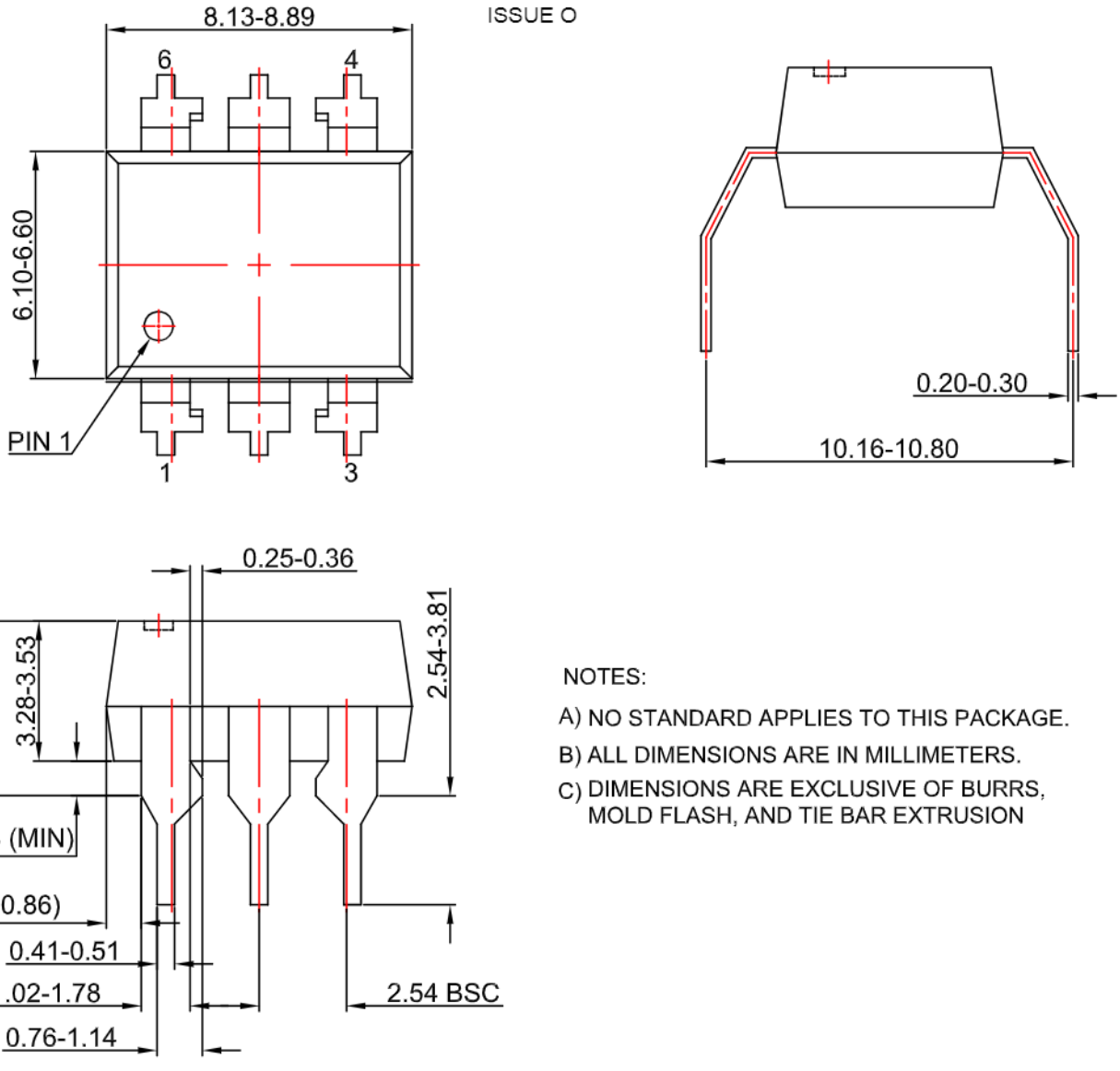
A) NO STANDARD APPLIES TO THIS PACKAGE.

B) ALL DIMENSIONS ARE IN MILLIMETERS.

C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

PACKAGE DIMENSIONS

PDIP6 8.51x6.35, 2.54P
CASE 646BZ
ISSUE O



NOTES:

A) NO STANDARD APPLIES TO THIS PACKAGE.

B) ALL DIMENSIONS ARE IN MILLIMETERS.

C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910

ON Semiconductor Website: **www.onsemi.com**

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative